Data Sheet

### November 30, 2005

# 100MHz, JFET Input, High Slew Rate, Uncompensated, Operational Amplifier

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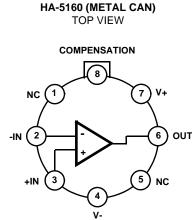
The HA-5160 is a wideband, uncompensated, operational amplifier with FET/Bipolar technologies and Dielectric Isolation. This monolithic amplifier features superior high frequency capabilities further enhanced by precision laser trimming of the input stage to provide excellent input characteristics. This device has excellent phase margin at a closed loop gain of 10 without external compensation.

The HA-5160 offers a number of important advantages over similar FET input op amps from other manufacturers. In addition to superior bandwidth and settling characteristics, the Intersil devices have nearly constant slew rate, bandwidth, and settling characteristics over the operating temperature range. This provides the user predictable performance in applications where settling time, full power bandwidth, closed loop bandwidth, or phase shift is critical. Note also that Intersil specified all parameters at ambient (rather than junction) temperature to provide the designer meaningful data to predict actual operating performance.

Complementing the HA-5160's predictable and excellent dynamic characteristics are very low input offset voltage, very low input bias current, and a very high input impedance. This ideal combination of features make these amplifiers most suitable for precision, high speed, data acquisition system designs and for a wide variety of signal conditioning applications. The HA-5160 provides excellent performance for applications which require both precision and high speed performance.

Military version (/883) data sheets are available upon request.

# Pinout



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NOTE: Case connected to V-

Features

- Wide Gain Bandwidth (A_V $\geq$ 10) 100MHz
+ High Slew Rate $\ldots \ldots \ldots 120 V/\mu s$
• Settling Time
Power Bandwidth 1.9MHz
• Offset Voltage 1.0mV
• Bias Current
Compensation Pin for Unity Gain Canability

#### Compensation Pin for Unity Gain Capability

### Applications

- Video and RF Amplifiers
- Data Acquisition
- Pulse Amplifiers
- Precision Signal Generation

### **Ordering Information**

PART NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #	
HA2-5160-5	HA2-5160-5	0 to 75	8 Pin Metal Can	T8.C	

### **Absolute Maximum Ratings**

Voltage Between V+ and V	10V
Differential Input Voltage	10V
Peak Output Current Full Short Circuit Protect	tion

### **Operating conditions**

Temperature Ranges	
HA-5160-5	0°C to 75°C
Supply Voltage Range (Typical)	$\pm 7V$ to $\pm 18V$

### **Thermal Information**

Thermal Resistance (Typical, Note 1)	θ <sub>JA</sub> (°C/W)	θ <sub>JC</sub> (°C/W)
Metal Can Package	155	67
Maximum Junction Temperature		175°C
Maximum Storage Temperature Range .	6	5°C to 150°C
Maximum Lead Temperature (Soldering 1	0s)	300°C

#### **Die Characteristics**

Number of Transistors	82
Substrate Potential (Powered Up) Floa	uting

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1.  $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.

### $\label{eq:superior} \textbf{Electrical Specifications} \quad V_{SUPPLY} = \pm 15V, \, \text{Unless Otherwise Specified}$

PARAMETER	TEST CONDITIONS	TEMP. (°C)	MIN	ТҮР	МАХ	UNITS
INPUT CHARACTERISTICS						
Offset Voltage		25	-	1	3	mV
		Full	-	3	5	mV
Offset Voltage Average Drift		Full	-	20	-	μV/°C
Bias Current		25	-	20	50	pА
		Full	-	5	10	nA
Offset Current		25	-	2	10	pА
		Full	-	2	5	nA
Input Capacitance		25	-	5	-	pF
Input Resistance		25	-	10 <sup>12</sup>	-	Ω
Common Mode Range		Full	±10	±11	-	V
TRANSFER CHARACTERISTICS		I		I	I	
Large Signal Voltage Gain	$V_{OUT} = \pm 10V,$	25	75	150	-	kV/V
	$R_{L} = 2k\Omega$	Full	60	100	-	kV/V
Common Mode Rejection Ratio	$V_{CM} = \pm 10V$	Full	74	80	-	dB
Minimum Stable Gain		25	10	-	-	V/V
Gain Bandwidth Product	$A_V \ge 10$	Full	-	100	-	MHz
OUTPUT CHARACTERISTICS		1	1	1	1	
Output Voltage Swing	$R_L = 2k\Omega$	25	±10	±11	-	V
		Full	±10	±11	-	V
Output Current	$V_{OUT} = \pm 10V$	25	±10	±20	-	mA
Output Short Circuit Current		25	-	±35	-	mA
Full Power Bandwidth (Note 2)	$V_{OUT} = \pm 10V,$ $R_L = 2k\Omega$	25	1.6	1.9	-	MHz
Output Resistance	Open Loop	25	-	50	-	Ω
TRANSIENT RESPONSE (Note 3)		1	1		1	
Rise Time	A <sub>V</sub> = +10	25	-	20	-	ns
Slew Rate	A <sub>V</sub> = +10	25	100	120	-	V/µs
Settling Time (Note 4)	A <sub>V</sub> = -10	25	-	280	-	ns

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Electrical Specifications  $V_{SUPPLY} = \pm 15V$ , Unless Otherwise Specified (Continued)

PARAMETER	TEST CONDITIONS	TEMP. (°C)	MIN	ТҮР	МАХ	UNITS		
POWER SUPPLY CHARACTERISTICS								
Supply Current		Full	-	8	10	mA		
Power Supply Rejection Ratio	$V_S = \pm 10V$ to $\pm 20V$	25	74	86	-	dB		

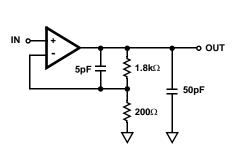
NOTES:

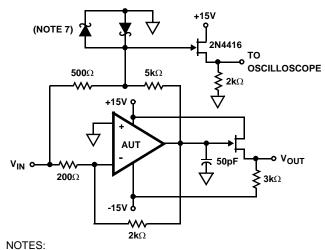
 $\frac{\text{Slew Rate}}{2\pi V}_{\text{PEAK}}$ 2. Full Power Bandwidth guaranteed, based on slew rate measurement using: FPBW =

3. Refer to Test circuits section of the data sheet.

4. Settling Time is measured to 0.2% of final value for a 10V output step.

### **Test Circuits and Waveforms**



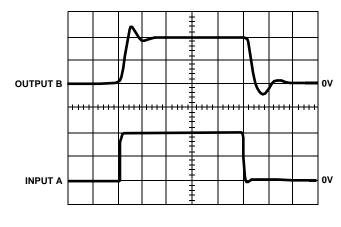


5.  $A_V = -10$ .

6. Feedback and summing resistors should be 0.1% matched.

7. Clipping diodes are optional. HP5082-2810 recommended.

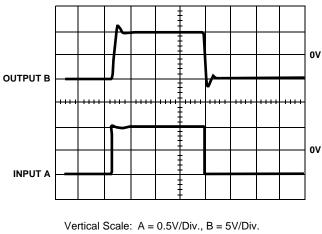
#### FIGURE 2. SETTLING TIME TEST CIRCUIT



Vertical Scale: A = 10mV/Div., B = 100mV/Div. Horizontal Scale: 100ns/Div.

SMALL SIGNAL RESPONSE

FIGURE 1. LARGE AND SMALL SIGNAL RESPONSE TEST CIRCUIT



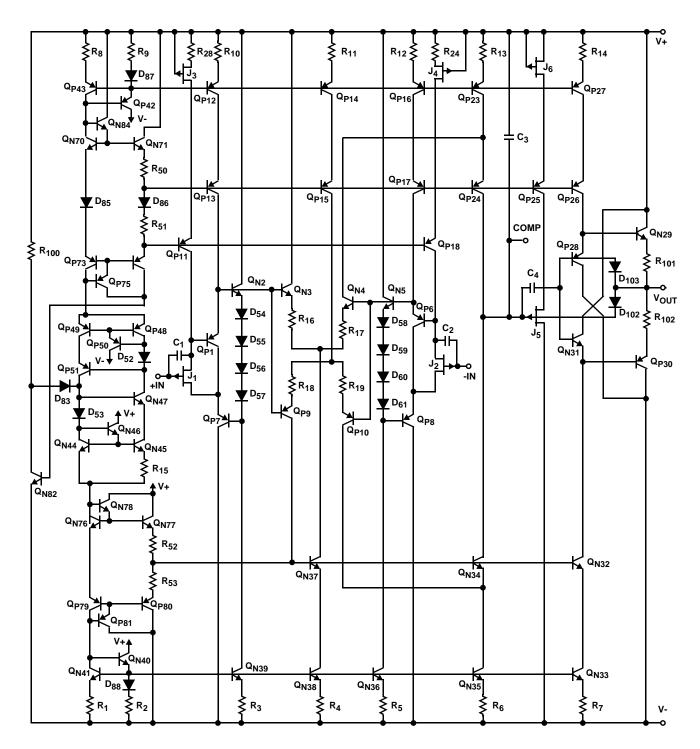
Horizontal Scale: 500ns/Div.

#### LARGE SIGNAL RESPONSE

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# Schematic Diagram



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### Application Information

### **Power Supply Decoupling**

Although not absolutely necessary, it is recommended that all power supply lines be decoupled with  $0.01\mu$ F ceramic capacitors to ground. Decoupling capacitors should be located as near to the amplifier terminals as possible.

#### Stability

The phase margin of the HA-5160 will be improved by connecting a small capacitor (>10pF) between the output

and the inverting input of the device This small capacitor compensates for the input capacitance of the FET.

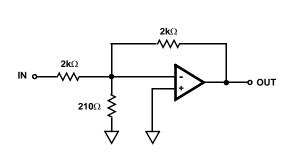
### **Capacitive Loads**

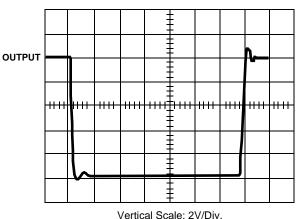
When driving large capacitive loads (>100pF), it is suggested that a small resistor ( $\approx$ 100 $\Omega$ ) be connected in series with the output of the device and inside the feedback loop.

### **Power Supply Minimum**

The absolute supply minimum is  $\pm 6V$  and the safe level is  $\pm 7V$ .





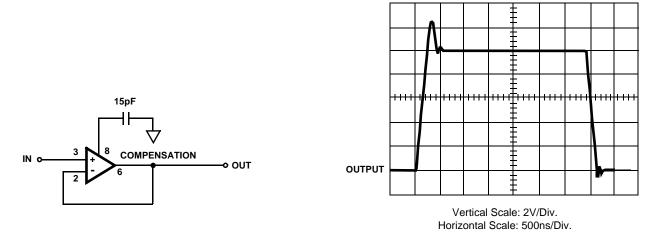


Horizontal Scale: 500ns/Div.

FIGURE 3A. INVERTING UNITY GAIN CIRCUIT

#### FIGURE 3B. INVERTING UNITY GAIN PULSE RESPONSE

FIGURE 3. GAIN OF -1



NOTE: Values were determined experimentally for optimum speed and settling time.

FIGURE 4A. NONINVERTING UNITY GAIN CIRCUIT

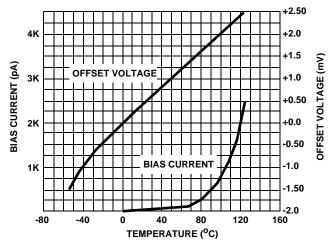
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FIGURE 4B. NONINVERTING UNITY GAIN PULSE RESPONSE

FIGURE 4. GAIN OF +1

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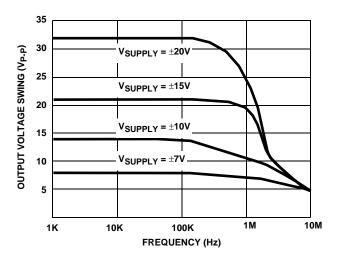
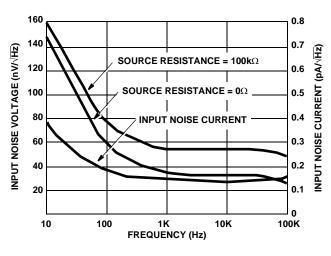
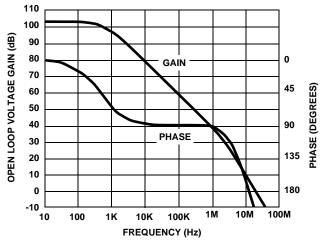


FIGURE 7. OUTPUT VOLTAGE SWING vs FREQUENCY

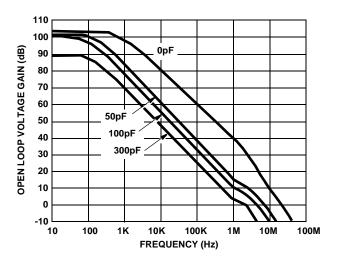




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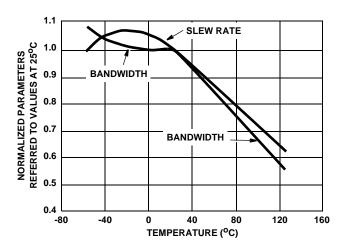


FIGURE 10. NORMALIZED AC PARAMETERS vs TEMPERATURE

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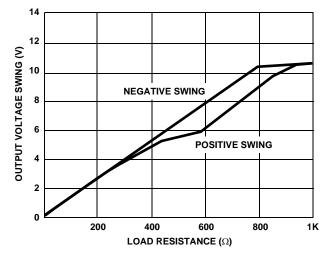


FIGURE 11. OUTPUT VOLTAGE SWING vs LOAD RESISTANCE

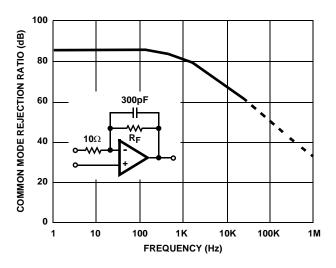


FIGURE 13. COMMON MODE REJECTION RATIO vs FRE-QUENCY

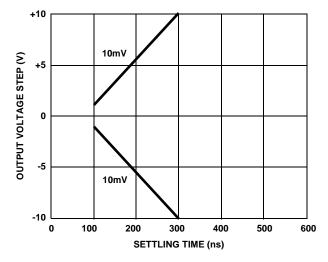


FIGURE 12. SETTLING TIME FOR VARIOUS OUTPUT STEP VOLTAGES

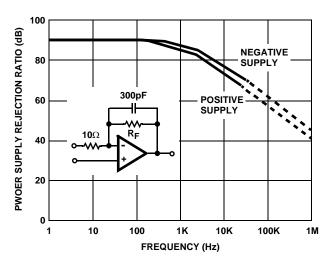


FIGURE 14. POWER SUPPLY REJECTION RATIO vs FRE-QUENCY

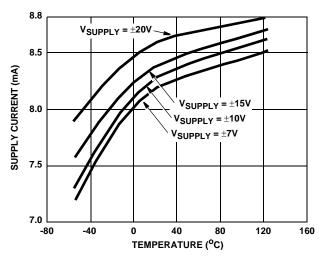
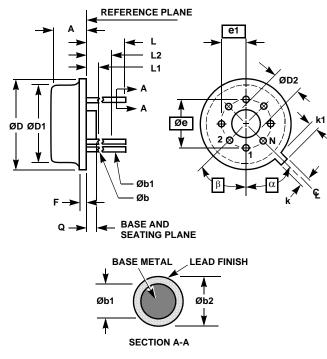


FIGURE 15. POWER SUPPLY CURRENT vs TEMPERATURE

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# Metal Can Packages (Can)



#### NOTES:

- (All leads) Øb applies between L1 and L2. Øb1 applies between L2 and 0.500 from the reference plane. Diameter is uncontrolled in L1 and beyond 0.500 from the reference plane.
- 2. Measured from maximum diameter of the product.
- 3.  $\alpha$  is the basic spacing from the centerline of the tab to terminal 1 and  $\beta$  is the basic spacing of each lead or lead position (N -1 places) from  $\alpha$ , looking at the bottom of the package.
- 4. N is the maximum number of terminal positions.
- 5. Dimensioning and tolerancing per ANSI Y14.5M 1982.
- 6. Controlling dimension: INCH.

#### **T8.C** MIL-STD-1835 MACY1-X8 (A1) 8 LEAD METAL CAN PACKAGE

	INC	INCHES MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX	NOTES
А	0.165	0.185	4.19	4.70	-
Øb	0.016	0.019	0.41	0.48	1
Øb1	0.016	0.021	0.41	0.53	1
Øb2	0.016	0.024	0.41	0.61	-
ØD	0.335	0.375	8.51	9.40	-
ØD1	0.305	0.335	7.75	8.51	-
ØD2	0.110	0.160	2.79	4.06	-
е	0.200 BSC		5.08	-	
e1	0.100	BSC	2.54 BSC		-
F	-	0.040	-	1.02	-
k	0.027	0.034	0.69	0.86	-
k1	0.027	0.045	0.69	1.14	2
L	0.500	0.750	12.70	19.05	1
L1	-	0.050	-	1.27	1
L2	0.250	-	6.35	-	1
Q	0.010	0.045	0.25	1.14	-
α	45 <sup>0</sup>	BSC	45 <sup>0</sup> BSC		3
β	45 <sup>0</sup>	BSC	45 <sup>0</sup>	BSC	3
Ν	8	3		8	4

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